# 

## (11) EP 4 223 694 A1

(12)

## **EUROPEAN PATENT APPLICATION**

(43) Date of publication: 09.08.2023 Bulletin 2023/32

(21) Application number: 23154483.4

(22) Date of filing: 01.02.2023

(51) International Patent Classification (IPC):

C01B 32/991 (2017.01) B82Y 30/00 (2011.01)

B82Y 40/00 (2011.01)

(52) Cooperative Patent Classification (CPC): C01B 32/991; B82Y 30/00; B82Y 40/00

(84) Designated Contracting States:

AL AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC ME MK MT NL NO PL PT RO RS SE SI SK SM TR

Designated Extension States:

BA

**Designated Validation States:** 

KH MA MD TN

(30) Priority: 07.02.2022 PL 44031022

(71) Applicant: Akademia Gorniczo-Hutnicza im. Stanislawa Staszica w Krakowie 30-059 Krakow (PL) (72) Inventors:

KOZIEN, Dawid
 31-586 Kraków (PL)

 PEDZICH, Zbigniew 30-619 Kraków (PL)

JELEN, Piotr
 32-050 Skawina (PL)

(74) Representative: Augustyniak, Magdalena Anna et al

Polservice Kancelaria Rzecznikow Patentowych sp. z o.o. Bluszczanska 73 00-712 Warszawa (PL)

## (54) METHOD OF OBTAINING BORON CARBIDE NANOPARTICLES

(57) A method of obtaining boron carbide nanoparticles in the process of direct synthesis from boron and carbon powders, which are heated at the temperature of 1400-1700°C and next comminuted, is characterized by the fact that in a graphite crucible, on a graphite pad, the following are placed successively: a layer of amorphous boron powder, and next a layer of carbon in the form of amorphous carbon black, wherein the ratio of amorphous boron to amorphous carbon black is 4: 1, and all is heated for 10 minutes to 4 hours. From the obtained bed of the product, the layer at the lowest, near the bottom of the crucible, distinguished by a light gray colour and showing

the greatest compactness and hardness, is subjected to intensive milling using steel elements in an isopropanol environment for a period of 6 to 24 hours, and next is subjected to chemical etching, using successively: concentrated HCI, next concentrated HNO<sub>3</sub> and again concentrated HCI. The resulting powder is subjected to repeated washing out using distilled water until achieving pH of the suspension from 6.5-7.5, and in the final step, the suspension is subjected to intensive centrifugation at a speed of 5000 to 12000 rpm, with a centrifugation time from 5 minutes to 4 hours, achieving rounded off grains of boron carbide from 50 to 200 nm in size.

EP 4 223 694 A1

**[0001]** The subject of the invention is a method of obtaining boron carbide nanoparticles, intended especially

1

for producing of wear-resistant machine parts and devices

**[0002]** As is known from scientific publications, among others F. Thévenot, titled: "Boron carbide - A comprehensive review", Journal of the European Ceramic Society, 1990, vol.6 (4), boron carbide occurs in the form of numerous crystalline phases. The general formula of boron carbide is presented as  $B_nC_m$ , where n comprises the ranges: 24-2.57, 11.5-4, 6.5-4, 9-4 and 10.1-4, m takes the values 1-3, and the most often occurring phases are  $B_6C$ ,  $B_2C_2$ , BC,  $B_3C$ ,  $B_7C$ ,  $B_{12}C$ ,  $B_{50}C_2$ ,  $B_{13}C_3$  and  $B_{13}C_2$ . Boron carbide powders are used, among others, to produce dense, polycrystalline sinters, which have found a number of industrial applications due to their specific properties, such as extreme hardness (28-35 GPa), relatively low density (~2.52 g/cm³), high Young's mod-

ulus (450-470 GPA) and high chemical resistance.

[0003] Boron carbide powders are currently synthesized by a number of methods, among others, by carbothermic reduction, magnesothermic reduction, synthesis from elements, gas phase synthesis, synthesis from polymer precursors, liquid phase reaction, ion beam synthesis, VLS method (Vapour-Liquid-Solid Growth). A commonly used method for synthesis of boron carbide is synthesis by carbothermic reduction, which uses boric acid H<sub>3</sub>BO<sub>3</sub> as a boron precursor and petroleum coke as a carbon precursor. The optimum ratio of boric acid to petroleum coke is 1:8. At higher boron to carbon ratios, achieving pure powder without the addition of free carbon is possible, however due to the excessive boron content and its melting point, recovery of the achieved boron carbide powder from the furnace is impossible, due to fusion of the powders into the graphite crucibles. The addition of a small amount of sodium chloride is then usually used: 1-5% by weight, which significantly improves the process yield by lowering the content of residual free carbon and at the same time reducing the energy requirement by 20%. Unfortunately, simultaneously during the direct synthesis of boron-enriched boron carbide, there is a loss of boron in the furnace, which causes the contamination of the reactor and the losses of a raw material. For this reason, this process has not found wider application in the commercial synthesis of boron carbide. The boron carbide powders obtained by this method are characterized by a particle size above 1  $\mu m$  and very often contain unreacted boron.

**[0004]** A method for producing submicron sized boron carbide powder from boric acid  $H_3BO_3$  or boron oxide  $B_2O_3$  is known from patent specification US4804525A, and the carbon source useful for the  $B_4C$  synthesis is any carbon-containing material that will form carbon when heated. The carbon source used during the synthesis must be characterized by high purity and does not contain heavy metals (Fe, Cr, Ni), their content is maxi-

mum of 500 ppm, and the most preferable concentration is below 200 ppm. Increasing the chemical purity of boron carbide requires the removal of residual carbon remaining after synthesis. To eliminate carbon in the synthesis products, an excess of  $\rm B_2O_3$  is used in the reaction to minimize the carbon content to 1% in the achieved powder. After synthesis,  $\rm B_2O_3$  is recycled or reused to the synthesis of of boron carbide.

[0005] Another known method, is a synthesis of boron carbide from boron and carbon powders, which are heated and next comminuted. For example, patent description US3914371A discloses a method for producing of boron carbide with different stoichiometric configurations. The synthesis method is characterized by mixing 78% by weight of boron particles and 22% by weight of carbon, in the temperature range from 1250 to 1700°C, with heating rate from 100 to 200°C, over a period of 1 hour. The boron carbide particles obtained in this manner can be used to produce dense sinters by hot pressing at the temperature in the range from 1800 to 2000°C.

[0006] Although many methods of boron carbide synthesis are known and used, most of them do not allow to achieve a high purity powder. A tremendous problem of the currently used synthesis methods is, in particular, high agglomeration and aggregation of the obtained products after synthesis with particle size above 3-5 µm. For this reason, intensive mechanical processing of the achieved powders is necessary, which in turn causes their significant contamination with iron molecules, associated with the use of steel grinding mediums for milling hard agglomerates. Commercially achieved boron carbide powders are characterized by a purity of 96-98% and a particle size above 1 µm. Long-term purification methods, generate increase of production costs and make it impossible to achieve boron carbide particles with a size below 1  $\mu$ m, despite increased milling time. Products achieved from such powders have a low density and are porous, which in turn leads to their low strength and poor resistance to brittle cracking.

**[0007]** The aim of the invention is to achieve boron carbide particles of submicron size (less than 1  $\mu$ m) and high purity, not achievable previously by methods commonly used, what will improve the properties of products obtained from these powders and increase the possibilities of its application.

[0008] The gist of the method of obtaining boron carbide nanoparticles by direct synthesis process from boron and carbon powders, which are heated at the temperature of 1400-1700°C and next comminuted, is characterized by the fact that in a graphite crucible, on a graphite pad, the following are placed successively: a layer of amorphous boron powder, and next a layer of carbon in the form of amorphous carbon black, wherein the ratio of amorphous boron to amorphous carbon black is 4:1, and all of it is heated for 10 minutes to 4 hours. From the obtained, according to the kinetics of the reaction, bed of the product being in the form of three clearly distinguishable layers, the top two layers are poured

35

45

50

down and recycled and/or returned as a raw material for the re-synthesis of boron carbide, and the layer located at the lowest, near the bottom of the crucible, distinguished by a light gray colour and showing the greatest compactness and hardness, is subjected to intensive milling using steel elements in an isopropanol environment for a period of 6 to 24 hours, and next is subjected to chemical etching in order to wash out impurities in the form of iron ions derived from milling, using successively: concentrated HCI, next concentrated HNO3 and again concentrated HCI. The obtained powder is subjected to repeated washing out using distilled water until achieving pH of the suspension from 6.5 to 7.5, and in the final step the suspension is subjected to intensive centrifugation at speed from 5000 to 12000 rpm, with centrifugation time from 5 minutes to 4 hours, achieving rounded off grains of boron carbide from 50 to 200 nm in size.

[0009] The method according to the invention allows to achieve boron-rich boron carbide powder having high purity and small grain size (below 1 μm), with rounded off shapes. The advantage of the proposed solution is the possibility to precisely control the morphology of the obtained particles through the parallel use of milling and chemical etching. The obtained powder, due to size and shape of the grains, can significantly improve the sinterability of boron carbide-based composites intended for producing of wear-resi stant machine parts and devices. These features are also beneficial for medical applications, such as drug carriers. Furthermore, the configuration of the substrates bed allows for complete utilization of boron during synthesis and does not cause furnace contamination resulting from increased boron vapor pressure, since all boron reacts with carbon monoxide during synthesis, which is assured by a layer of carbon black over a layer of boron and it is visible as synthesis effect.

**[0010]** The method of obtaining boron carbide nanoparticles according to the invention, is explained below in practical embodiments and in the figure, in which fig. 1 shows the XRD phase analysis of boron carbide obtained by the method described in example 1, fig. 2 - a transmission electron microscope (TEM) image of boron carbide powder obtained by the method described in example 1, fig. 3 - the XRD phase analysis of boron carbide obtained by the method described in example 2, and fig. 4 - the transmission electron microscope (TEM) image of boron carbide powder obtained by the method described in example 2.

## Example 1

**[0011]** The following powders were prepared: amorphous boron (Sigma Aldrich p.a.) and technical carbon black P-803 (Thujmazy). A phase composition analysis performed showed that the commercial boron powder consisted of 3 phases: beta boron (card number 98-004-3431 according to ISCD database), boric acid (card number 98-002-4711 according to the ICSD data-

base) and boron (card number 98-002-2300 according to ICSD database), while the carbon black was fully amorphous. Direct synthesis from the above-mentioned powders was used to produce boron carbide. A graphite pad was placed at the bottom of the graphite crucible, a layer of amorphous boron powder in the amount of 12 g was placed on it, and next, after levelling the surface, a layer of amorphous carbon black in the amount of 3 g. This procedure simultaneously reduces the diffusion of boron in the bed and its loss during synthesis in the furnace. It also has a significant effect on the morphology of the achieved powder because the use of such method of synthesis reduces the agglomeration and aggregation of the resulting boron carbide grains and allows to achieve powder of a high purity. The crucible was placed in the graphite furnace and heated at the temperature of 1650°C under argon atmosphere for 1 hour. The bed containing three layers was achieved. The layer I, located at the lowest, near the bottom of the crucible, was distinguished by its light gray colour and showed clearly greater compactness and hardness than the other layers. The top two layers (layer II and layer III) showed dark gray to black in colour and were characterized by a looser consistency compared to the layer I. The layer III was composed of a loose powder entirely consisting of carbon black as the studies showed. The layer II was recycled and the layer III was returned as a raw material for the re-synthesis of boron carbide. The layer I, in the form of powder with an average particle size of 500 nm, was subjected to intensive milling using steel elements in a rotary-vibrating mill, in an isopropanol environment, for a period of 24 hours. Next the powder was subjected to chemical etching in order to wash out impurities in the form of iron ions derived from milling, using successively: concentrated HCI (38%) for 3 hours, next concentrated HNO<sub>3</sub> (65%) for 3 hours and again concentrated HCI (38%) for 3 hours. The achieved product, as confirmed by the XRD phase analysis (fig. 1), consisted exclusively of the  $\mathsf{B}_{13}\mathsf{C}_2$  phase, considered the most stable and with a high carbon solubility in the structure, which is particularly important for potential medical applications, and does not possess any of impurities detectable by X-ray diffraction and X-ray fluorescence. Next the product was washed out 7 times using distilled water until achieving pH = 7, after which the obtained suspension was subjected to intensive centrifugation for 45 minutes at 5000 rpm (centrifuge MPW-341, MPW Med. Instruments). A boron carbide powder of almost 100% purity, with rounded off grains, average particle size less than 150 nm was achieved, the TEM image of which is shown in fig. 2.

## Example 2

**[0012]** Direct synthesis from the powders described in example 1 was used to produce of boron carbide. A graphite pad was placed at the bottom of the graphite crucible, a layer of amorphous boron powder in the amount of 12 g was placed on it, and next, after levelling

the surface, a layer of amorphous carbon black in the amount of 3 g. The crucible was placed in the furnace graphite and heated at the temperature of 1600°C under argon atmosphere for 3 hours. A bed containing three layers, analogous to those described in example 1 was achieved. The layer II was recycled and the layer III was returned as a raw material for the re-synthesis of boron carbide. The layer I, in the form of powder with an average particle size of 500 nm, was subjected to intensive milling using steel elements in a rotary-vibrating mill, in an isopropanol environment, for a period of 24 hours. Then the powder was subjected to chemical etching in order to wash out impurities in the form of iron ions derived from milling, using successively: concentrated HCI (38%) for 3 hours, next concentrated HNO<sub>3</sub> (65%) for 3 hours and again concentrated HCI (38%) for 3 hours. The XRD phase analysis of the achieved product (fig. 3), showed the presence of 3 phases: a rhombohedral boron carbide phase B<sub>13</sub>C<sub>2</sub> in the amount of 87.3% by weight, a tetragonal boron carbide phase of stoichiometry B<sub>48</sub>(B<sub>2</sub>C<sub>2</sub> in the amount of 11.4% by weight, and a small amount (1.3% by weight) of a graphite-like phase. The product was then washed out 7 times using distilled water until achieving pH = 7, after which the obtained suspension was subjected to intensive centrifugation for 1.5 hours at 10,000 rpm (centrifuge MPW-341, MPW Med. Instruments). The boron carbide powder with a purity of more than 99%, having rounded off grains, an average particle size of less than 85 nm was achieved, the TEM image of which is shown in fig. 4.

5

obtained powder is subjected to repeated washing out using distilled water until achieving pH of the suspension from 6.5 to 7.5, and in final step, the suspension is subjected to intensive centrifugation at a speed of 5000 to 12000 rpm, with a centrifugation time from 5 minutes to 4 hours, achieving rounded off grains of boron carbide from 50 to 200 nm in size.

#### **Claims**

- 1. method of obtaining boron carbide nanoparticles by direct synthesis process from boron and carbon powders, which are heated at the temperature of 1400-1700°C and next comminuted characterized in that in a graphite crucible, on a graphite pad, the following are placed successively: a layer of amorphous boron powder, and next a layer of carbon in the form of amorphous carbon black, wherein a ratio of amorphous boron to amorphous carbon black is 4:1, and all of it is heated for 10 minutes to 4 hours, after which from the obtained bed of the product in the form of three clearly distinguishable layers, the top two layers are poured down and undergo recycling and/or are returned as a raw material to the resynthesis of boron carbide, and the layer at the lowest, near the bottom of the crucible, distinguished by its light gray colour and showing the greatest compactness and hardness, is subjected to intensive milling using steel elements in an isopropanol environment for a period of 6 to 24 hours, and next is subjected to chemical etching to wash out impurities in the form of iron ions derived from milling, using successively: concentrated HCI, next concentrated HNO<sub>3</sub> and again concentrated HCI, after which the

30

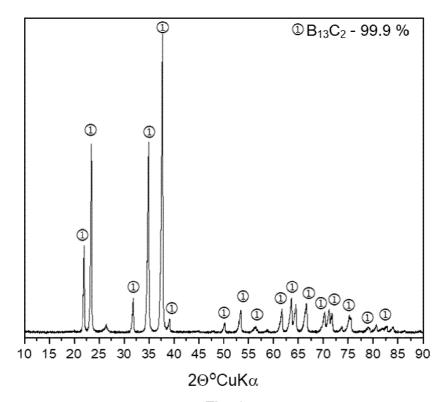


Fig. 1

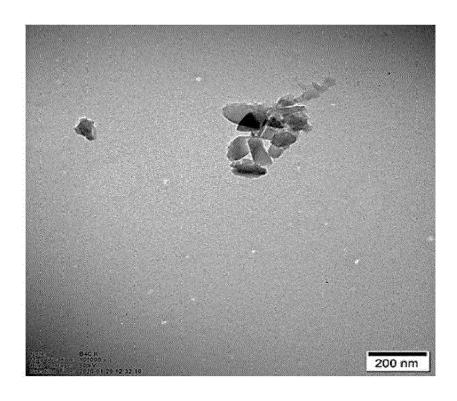


Fig.2

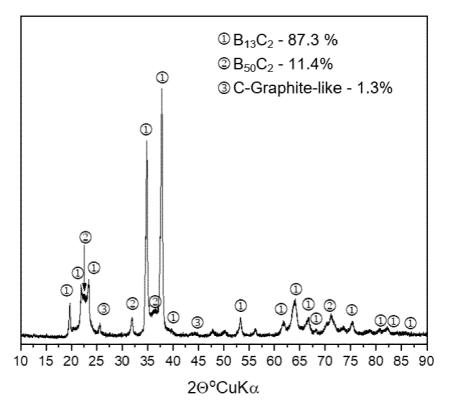


Fig. 3

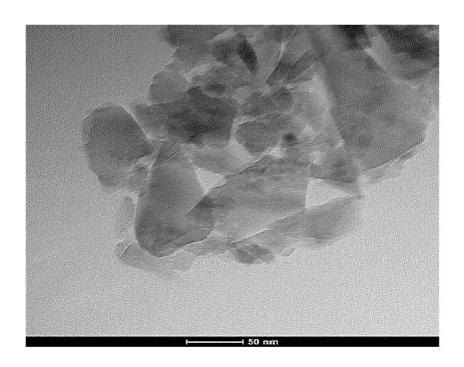


Fig. 4



## **EUROPEAN SEARCH REPORT**

**Application Number** 

EP 23 15 4483

		ERED TO BE RELEVANT		
Category	Citation of document with in of relevant pass	ndication, where appropriate, ages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (IPC)
A	DATABASE WPI Week 2020065 Thomson Scientific, AN 2020-671784 XP002809556, -& CN 111 377 449 A NEW MATERIAL TECHNO 7 July 2020 (2020-0 * abstract * * citations rerfer translation into En paragraphs [0003] - * the whole document	London, GB;  (INNER MONGOLIA YUAN LOGY CO LTD) 7-07)  to the machine glish; [0012] * t *	1 CI	INV. C01B32/991 B82Y30/00 B82Y40/00
A	WO 2008/102357 A2 ( [IL]; PRILUTSKY EMA 28 August 2008 (200 * claim 5 * * the whole documen	8-08-28)	1	
A	DATABASE WPI Week 201989 Thomson Scientific, AN 2019-88847M XP002809557, -& CN 110 357 106 A 22 October 2019 (20 * abstract; claim 1 * citations refer t translation into En * the whole document	(UNIV YANSHAN) 19-10-22) ; examples 1,2 * o the machine glish *	1	TECHNICAL FIELDS SEARCHED (IPC)  C01B B82Y
	The present search report has	·		Francisco
	Place of search	Date of completion of the search		Examiner
	The Hague	19 June 2023		raub, Thomas
X : part Y : part docu A : tech O : non	ATEGORY OF CITED DOCUMENTS icularly relevant if taken alone icularly relevant if combined with anot iment of the same category inological background -written disclosure rmediate document	E : earlier patent after the filing her D : document cit L : document cit	ed in the application ed for other reasons	lished on, or

page 1 of 2



## **EUROPEAN SEARCH REPORT**

**Application Number** 

EP 23 15 4483

Category	Citation of document with in			elevant	CLASSIFICATION OF THE APPLICATION (IPC)
	of relevant pass	ages	10	claim	APPLICATION (IPC)
A	DATABASE WPI		1		
	Week 201673				
	Thomson Scientific,	London, GB:			
	AN 2016-586104				
	XP002809558,				
	-& CN 105 924 175 B	(IINTV HERET E	NG)		
	12 February 2019 (2	•	AG,		
	* abstract; claim 1				
	* citations refer to				
	translation into En				
	* the whole document	-			
	" the whole documen				
					TECHNICAL FIELDS
					SEARCHED (IPC)
	The present search report has b	<u> </u>			
	Place of search	Date of completi			Examiner
	The Hague	19 June	2023	Str	aub, Thomas
C	ATEGORY OF CITED DOCUMENTS	<u></u>	theory or principle unde	rlying the in	nvention
~	ticularly relevant if taken alone		earlier patent document after the filing date		sneu on, or
X : part					
X : part Y : part	ticularly relevant if combined with anoth	ner D:	document cited in the a	pplication	
X : part Y : part doc A : tech	ticularly relevant if combined with anoth ument of the same category nnological background 1-written disclosure	L:	document cited for othe	r reasons	

page 2 of 2

## EP 4 223 694 A1

## ANNEX TO THE EUROPEAN SEARCH REPORT ON EUROPEAN PATENT APPLICATION NO.

EP 23 15 4483

5

This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EDP file on The European Patent Office is in no way liable for these particulars which are merely given for the purpose of information.

19-06-2023

10	cit	Patent document cited in search report		Publication Patent family member(s)				Publication date	
	CN	111377449	A	07-07-2020	NONE				
15	WO	2008102357	A2	28-08-2008	EP JP WO	2125663 2 2010520846 2 2008102357 2	A A2	02-12-2009 17-06-2010 28-08-2008	
	CN	110357106			NONE				
20	CN 	105924175			NONE				
25									
30									
35									
40									
45									
50									
55	FORM P0459								

For more details about this annex : see Official Journal of the European Patent Office, No. 12/82

## EP 4 223 694 A1

#### REFERENCES CITED IN THE DESCRIPTION

This list of references cited by the applicant is for the reader's convenience only. It does not form part of the European patent document. Even though great care has been taken in compiling the references, errors or omissions cannot be excluded and the EPO disclaims all liability in this regard.

## Patent documents cited in the description

US 4804525 A [0004]

• US 3914371 A [0005]

## Non-patent literature cited in the description

• **F. THÉVENOT.** Boron carbide - A comprehensive review. *Journal of the European Ceramic Society*, 1990, vol. 6 (4 **[0002]**